

Heisener.com

EDB4432BBBJ-1DAUT-F-R TR

EDB4432BBBJ-1DAUT-F-R TR Information

Part Number EDB4432BBBJ-1DAUT-F-R TR

Manufacturer Micron Technology Inc. Integrated Circuits (ICs) Category

Memory

Description IC DRAM 4G PARALLEL 533MHZ

Package

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









EDB4432BBBJ-1DAUT-F-R TR Specifications

	Report errors?
Supplier Device Package	-
Package / Case	-
Mounting Type	-
Operating Temperature	-40°C ~ 125°C (TC)
Voltage - Supply	1.14 V ~ 1.95 V
Access Time	-
Write Cycle Time - Word, Page	-
Clock Frequency	533MHz
Memory Interface	Parallel
Memory Size	4Gb (128M x 32)
Technology	SDRAM - Mobile LPDDR2
Memory Format	DRAM
Memory Type	Volatile
Series	-
Package	-
	Memory
Category	Integrated Circuits (ICs)
Manufacturer	Micron Technology Inc.
Manufacturer Part Number	EDB4432BBBJ-1DAUT-F-R TR

EDB4432BBBJ-1DAUT-F-R TR Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EDB4432BBBJ-1DAUT-F-R TR Payment Methods



















EDB4432BBBJ-1DAUT-F-R TR Shipping Methods













If you have any question about EDB4432BBBJ-1DAUT-F-R TR, please do not hesitate to contact us!

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